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LMC555 CMOS Timer

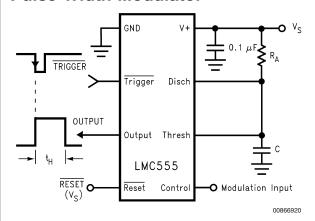
General Description

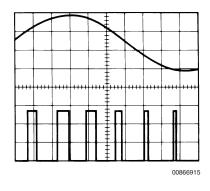
The LMC555 is a CMOS version of the industry standard 555 series general purpose timers. In addition to the standard package (SOIC, MSOP, and MDIP) the LMC555 is also available in a chip sized package (8 Bump micro SMD) using National's micro SMD package technology. The LMC555 offers the same capability of generating accurate time delays and frequencies as the LM555 but with much lower power dissipation and supply current spikes. When operated as a one-shot, the time delay is precisely controlled by a single external resistor and capacitor. In the stable mode the oscillation frequency and duty cycle are accurately set by two external resistors and one capacitor. The use of National Semiconductor's LMCMOS™ process extends both the frequency range and low supply capability.

Features

- Less than 1 mW typical power dissipation at 5V supply
- 3 MHz astable frequency capability
- 1.5V supply operating voltage guaranteed
- Output fully compatible with TTL and CMOS logic at 5V supply
- Tested to -10 mA, +50 mA output current levels
- Reduced supply current spikes during output transitions
- Extremely low reset, trigger, and threshold currents
- Excellent temperature stability
- Pin-for-pin compatible with 555 series of timers
- Available in 8-pin MSOP Package and 8-Bump micro SMD package

Pulse Width Modulator





Ordering Information

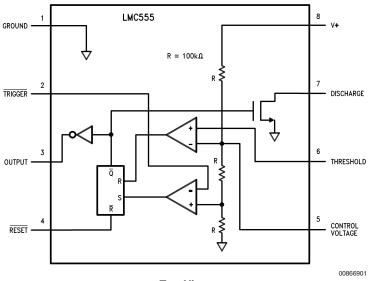
Package	Temperature Range	Package Marking	Transport Media	NSC Drawing		
	Industrial					
	-40°C to +85°C					
8-Pin Small Outline (SO)	LMC555CM	LMC555CM	Rails	M08A		
	LMC555CMX	LIVICSSSCIVI	2.5k Units Tape and Reel	IVIOOA		
8-Pin Mini Small Outline	LMC555CMM	LMC555CMM ZC5 1k U		MUA08A		
(MSOP)	LMC555CMMX	203	3.5k Units Tape and Reel	IVIOAUGA		
8-Pin Molded Dip (MDIP)	LMC555CN	LMC555CN	Rails	N08E		
8-Bump micro SMD	LMC555CBP	F1	250 Units Tape and Reel	BPA08EFB		
	LMC555CBPX	[[3k Units Tape and Reel			
8-Bump micro SMD	LMC555CTP	F02	250 Units Tape and Reel	TPA08EFA		
NOPB	LMC555CTPX	F02	3k Units Tape and Reel	IFAUGEFA		

Note: See Mil-datasheet MNLMC555-X for specifications on the military device LMC555J/883.

LMCMOS™ is a trademark of National Semiconductor Corp

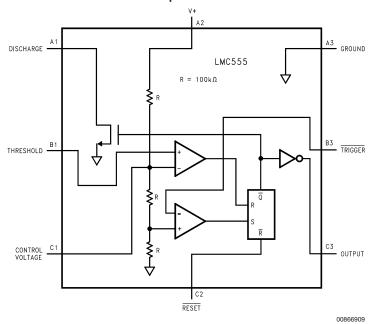
Connection Diagrams

8-Pin SOIC, MSOP, MDIP



Top View

8-Bump micro SMD



Top View (Bump Side Down)

Absolute Maximum Ratings (Notes 2, 3)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage, V+ 15V Input Voltages, V_{TRIG} , V_{RES} , V_{CTRL} , -0.3V to $V_S + 0.3V$ V_{THRESH} Output Voltages, V_O , V_{DIS} 15V Output Current IO, IDIS 100 mA Storage Temperature Range -65°C to +150°C Soldering Information MDIP Soldering (10 seconds) 260°C

Note: See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

Operating Ratings(Notes 2, 3)

SOIC, MSOP Vapor Phase (60 sec)

SOIC, MSOP Infrared (15 sec)

Termperature

-40°C to +85°C Range

Electrical Characteristics (Notes 1, 2)

Test Circuit, T = 25°C, all switches open, $\overline{\text{RESET}}$ to V_S unless otherwise noted

Symbol	Parameter	Conditions	Min	Тур	Max	Units (Limits)
Is	Supply Current	$V_S = 1.5V$		50	150	
		$V_S = 5V$		100	250	μΑ
		V _S = 12V		150	400	
V _{CTRL}	Control Voltage	V _S = 1.5V	0.8	1.0	1.2	
		$V_S = 5V$	2.9	3.3	3.8	V
		V _S = 12V	7.4	8.0	8.6	
V _{DIS}	Discharge Saturation Voltage	V _S = 1.5V, I _{DIS} = 1 mA		75	150	
		$V_S = 5V$, $I_{DIS} = 10$ mA		150	300	mV
V _{OL}	Output Voltage (Low)	V _S = 1.5V, I _O = 1 mA		0.2	0.4	
		$V_S = 5V, I_O = 8 \text{ mA}$		0.3	0.6	V
		$V_S = 12V, I_O = 50 \text{ mA}$		1.0	2.0	
V _{OH}	Output Voltage	$V_S = 1.5V, I_O = -0.25 \text{ mA}$	1.0	1.25		
	(High)	$V_{\rm S} = 5V, I_{\rm O} = -2 \text{ mA}$	4.4	4.7		V
		$V_S = 12V, I_O = -10 \text{ mA}$	10.5	11.3		
V _{TRIG}	Trigger Voltage	V _S = 1.5V	0.4	0.5	0.6	V
		V _S = 12V	3.7	4.0	4.3	V
I _{TRIG}	Trigger Current	$V_S = 5V$		10		pA
V _{RES}	Reset Voltage	V _S = 1.5V (Note 4)	0.4	0.7	1.0	V
		V _S = 12V	0.4	0.75	1.1	V
I _{RES}	Reset Current	$V_S = 5V$		10		pА
I _{THRESH}	Threshold Current	$V_S = 5V$		10		pA
I _{DIS}	Discharge Leakage	V _S = 12V		1.0	100	nA
t	Timing Accuracy	SW 2, 4 Closed				
		V _S = 1.5V	0.9	1.1	1.25	
		$V_S = 5V$	1.0	1.1	1.20	ms
		V _S = 12V	1.0	1.1	1.25	
Δt/ΔV _S	Timing Shift with Supply	$V_{S} = 5V \pm 1V$		0.3		%/V

215°C

220°C

Thermal Resistance (θ_{JA}) (Note 2)

SO, 8-Pin Small

Outline 169°C/W

MSOP, 8-Pin Mini Small

> Outline 225°C/W

MDIP, 8-Pin

Molded Dip 111°C/W

8-Bump micro

SMD 220°C/W

Maximum Allowable Power

Dissipation @25°C

MDIP-8 1126 mW SO-8 740 mW MSOP-8 555 mW

8 Bump micro

568 mW

Electrical Characteristics (Notes 1, 2)

Test Circuit, T = 25°C, all switches open, \overline{RESET} to V_S unless otherwise noted (Continued)

Symbol	Parameter	Conditions	Min	Тур	Max	Units (Limits)
Δt/ΔΤ	Timing Shift with	$V_S = 5V$		75		ppm/°C
	Temperature	$-40^{\circ}\text{C} \le \text{T} \le +85^{\circ}\text{C}$				
f _A	Astable Frequency	SW 1, 3 Closed, V _S = 12V	4.0	4.8	5.6	kHz
f _{MAX}	Maximum Frequency	Max. Freq. Test Circuit, V _S = 5V		3.0		MHz
t _R , t _F	Output Rise and	Max. Freq. Test Circuit		15		ns
	Fall Times	$V_{S} = 5V, C_{L} = 10 pF$				
t _{PD}	Trigger Propagation Delay	V _S = 5V, Measure Delay		100		ns
		from Trigger to Output		100		115

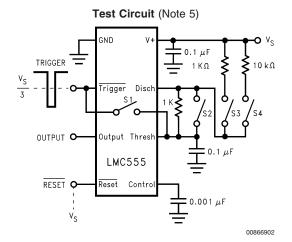
Note 1: All voltages are measured with respect to the ground pin, unless otherwise specified.

Note 2: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which guarantee specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not guaranteed for parameters where no limit is given, however, the typical value is a good indication of device performance.

Note 3: See AN-450 for other methods of soldering surface mount devices, and also AN-1112 for micro SMD considerations.

Note 4: If the $\overline{\text{RESET}}$ pin is to be used at temperatures of -20°C and below V_S is required to be 2.0V or greater.

Note 5: For device pinout please refer to table 1



Maximum Frequency Test Circuit (Note 5)

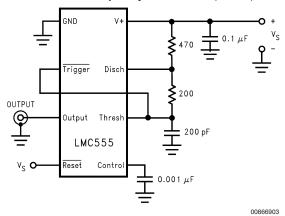


TABLE 1. Package Pinout Names vs. Pin Function

Pin Function	Package Pin numbers					
	8-Pin SO, MSOP, and MDIP	8-Bump micro SMD				
GND	1	А3				
Trigger	2	В3				
Output	3	СЗ				
Reset	4	C2				
Control Voltage	5	C1				
Threshold	6	B1				
Discharge	7	A1				
V ⁺	8	A2				

Application Information

MONOSTABLE OPERATION

In this mode of operation, the timer functions as a one-shot (Figure 1). The external capacitor is initially held discharged by internal circuitry. Upon application of a negative trigger pulse of less than 1/3 $\rm V_S$ to the $\overline{\rm Trigger}$ terminal, the flip-flop is set which both releases the short circuit across the capacitor and drives the output high.

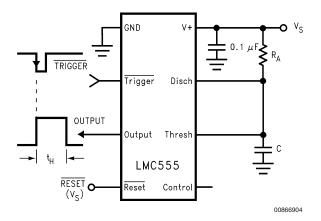
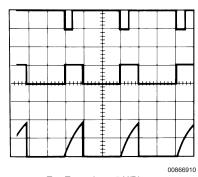


FIGURE 1. Monostable (One-Shot)

The voltage across the capacitor then increases exponentially for a period of $t_H = 1.1~R_A C$, which is also the time that the output stays high, at the end of which time the voltage equals $2/3~V_S$. The comparator then resets the flip-flop which in turn discharges the capacitor and drives the output to its low state. *Figure 2* shows the waveforms generated in this mode of operation. Since the charge and the threshold level of the comparator are both directly proportional to supply voltage, the timing internal is independent of supply.



 $V_{CC} = 5V$ Top Trace: Input 5 V/Div. TIME = 0.1 ms/Div. Middle Trace: Output 5 V/Div.

 $R_A = 9.1 \ k\Omega$ Bottom Trace: Capacitor Voltage 2 V/Div.

 $C=0.01~\mu\text{F}$

FIGURE 2. Monostable Waveforms

Reset overrides Trigger, which can override threshold. Therefore the trigger pulse must be shorter than the desired $t_{\rm H}$. The minimum pulse width for the Trigger is 20ns, and it is 400ns for the Reset. During the timing cycle when the output is high, the further application of a trigger pulse will not effect the circuit so long as the trigger input is returned high at least 10 μ s before the end of the timing interval. However the circuit can be reset during this time by the application of a

negative pulse to the reset terminal. The output will then remain in the low state until a trigger pulse is again applied. When the reset function is not use, it is recommended that it be connected to V_+ to avoid any possibility of false triggering. Figure 3 is a nomograph for easy determination of RC values for various time delays.

Note: In monstable operation, the trigger should be driven high before the end of timing cycle.

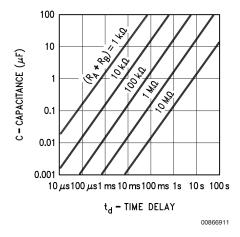


FIGURE 3. Time Delay

ASTABLE OPERATION

If the circuit is connected as shown in Figure 4 (Trigger and Threshold terminals connected together) it will trigger itself and free run as a multivibrator. The external capacitor charges through $R_{\rm A}+R_{\rm B}$ and discharges through $R_{\rm B}.$ Thus the duty cycle may be precisely set by the ratio of these two resistors.

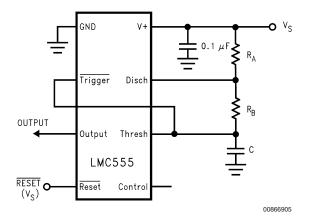
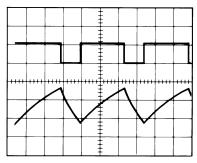


FIGURE 4. Astable (Variable Duty Cycle Oscillator)

In this mode of operation, the capacitor charges and discharges between 1/3 $\rm V_S$ and 2/3 $\rm V_S$. As in the triggered mode, the charge and discharge times, and therefore the frequency are independent of the supply voltage.

Figure 5 shows the waveform generated in this mode of operation.

Application Information (Continued)



00866912

 $V_{CC} = 5V$

Top Trace: Output 5 V/Div.

TIME = 20 μ s/Div. Bottom Trace: Capacitor Voltage 1 V/Div.

 $R_A = 3.9 \text{ k}\Omega$ $R_B = 9 \text{ k}\Omega$ $C = 0.01 \mu\text{F}$

FIGURE 5. Astable Waveforms

The charge time (output high) is given by

 $t_1 = 0.693 (R_A + R_B)C$

And the discharge time (output low) by:

$$t_2 = 0.693 (R_B)C$$

Thus the total period is:

$$T = t_1 + t_2 = 0.693 (R_A + R_B)C$$

The frequency of oscillation is:

$$f = \frac{1}{T} = \frac{1.44}{(R_A + 2\,R_B)\,C}$$

Figure 6 may be used for quick determination of these RC Values. The duty cycle, as a fraction of total period that the output is low, is:

$$D = \frac{R_B}{R_A + 2R_B}$$

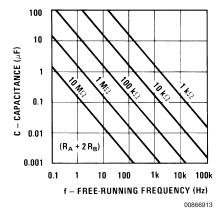
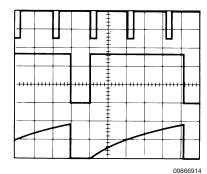


FIGURE 6. Free Running Frequency

FREQUENCY DIVIDER

The monostable circuit of *Figure 1* can be used as a frequency divider by adjusting the length of the timing cycle. *Figure 7* shows the waveforms generated in a divide by three circuit.



 $V_{CC} = 5V$

Top Trace: Input 4 V/Div.

TIME = 20 μ s/Div. R_A = 9.1 k Ω

Middle Trace: Output 2 V/Div. Bottom Trace: Capacitor 2 V/Div.

 $C = 0.01 \ \mu F$

FIGURE 7. Frequency Divider Waveforms

PULSE WIDTH MODULATOR

When the timer is connected in the monostable mode and triggered with a continuous pulse train, the output pulse width can be modulated by a signal applied to the Control Voltage Terminal. *Figure 8* shows the circuit, and in *Figure 9* are some waveform examples.

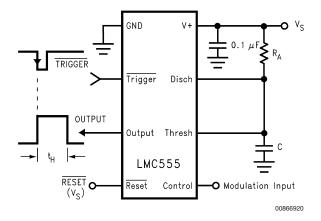
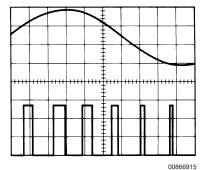


FIGURE 8. Pulse Width Modulator

Application Information (Continued)



 V_{CC} = 5V Top Trace: Modulation 1 V/Div. TIME = 0.2 ms/Div. Bottom Trace: Output Voltage 2 V/Div.

 $R_A = 9.1 \text{ k}\Omega$ $C = 0.01 \mu\text{F}$

FIGURE 9. Pulse Width Modulator Waveforms

PULSE POSITION MODULATOR

This application uses the timer connected for astable operation, as in *Figure 10*, with a modulating signal again applied to the control voltage terminal. The pulse position varies with the modulating signal, since the threshold voltage and hence the time delay is varied. *Figure 11* shows the waveforms generated for a triangle wave modulation signal.

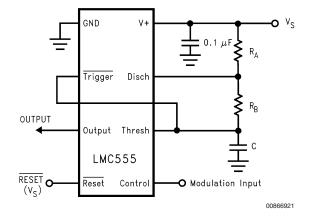
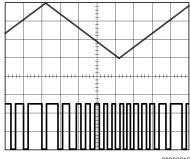


FIGURE 10. Pulse Position Modulator



V_{CC} = 5V Top Trace: Modulation Input 1 V/Div.
TIME = 0.1 ms/Div. Bottom Trace: Output Voltage 2 V/Div.

 $R_A = 3.9 \text{ k}\Omega$ $R_B = 3 \text{ k}\Omega$ $C = 0.01 \mu\text{F}$

FIGURE 11. Pulse Position Modulator Waveforms

50% DUTY CYCLE OSCILLATOR

The frequency of oscillation is $f = 1/(1.4 R_CC)$

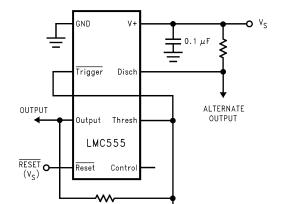
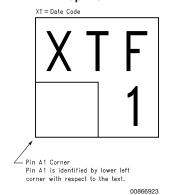


FIGURE 12. 50% Duty Cycle Oscillator

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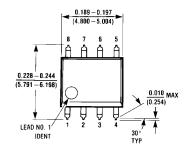
micro SMD Marking Orientation Top View

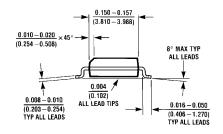


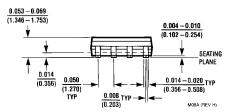
Bumps are numbered counter-clockwise

7

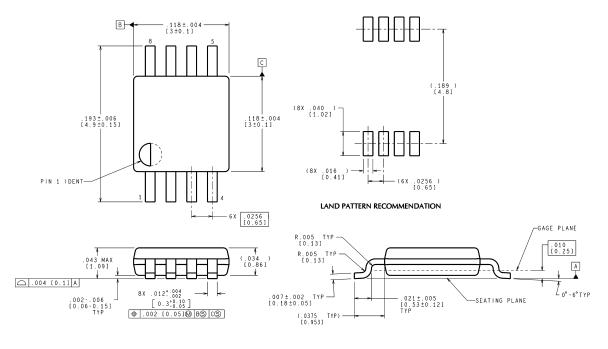
Physical Dimensions inches (millimeters) unless otherwise noted







Molded Small Outline (SO) Package (M) NS Package Number M08A

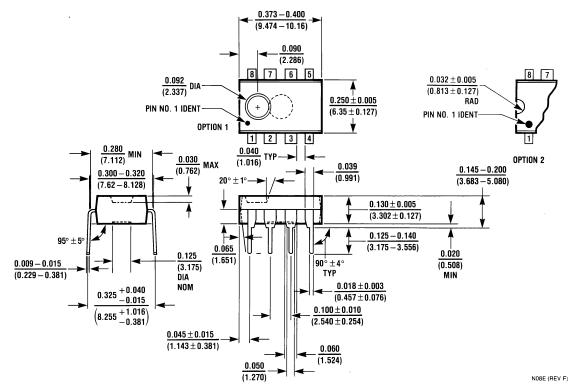


CONTROLLING DIMENSION IS INCH VALUES IN [] ARE MILLIMETERS

MUA08A (Rev E)

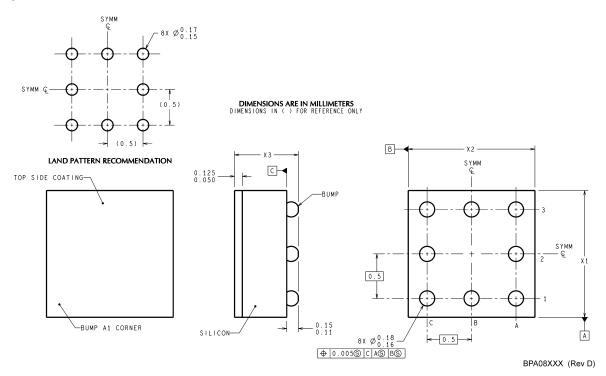
8-Pin (0.118" Wide) Molded Mini Small Outline Package NS Package Number MUA08A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Molded Dual-in-line Package (N) NS Package Number N08E

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

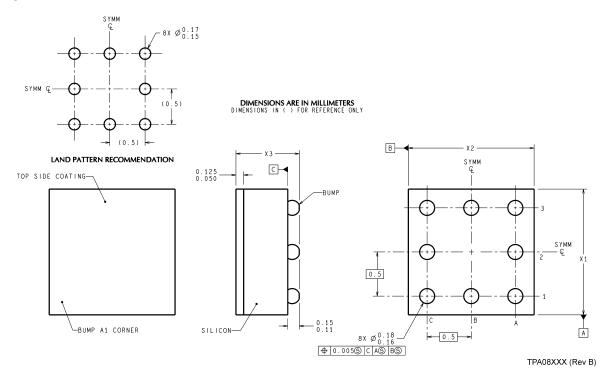


NOTES: UNLESS OTHERWISE SPECIFIED

- 1. EPOXY COATING
- 2. 63Sn/37Pb EUTECTIC BUMP
- 3. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.
- 4. PIN A1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION. REMAINING PINS ARE NUMBERED COUNTERCLOCKWISE.
- 5. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACKAGE HEIGHT.
- 6. REFERENCE JEDEC REGISTRATION MO-211, VARIATION BC.

8-Bump micro SMD Package NS Package Number BPA08EFB $X_1 = 1.387$ $X_2 = 1.412$ $X_3 = 0.850$

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NOTES: UNLESS OTHERWISE SPECIFIED

- 1. EPOXY COATING
- 2. FOR SOLDER BUMP COMPOSITION, SEE "SOLDER INFORMATION" IN THE PACKAGING SECTION OF THE NATIONAL SEMICONDUCTOR WEB PAGE (www.national.com).
- 3. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.
- 4. PIN A1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION.
- 5. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACKAGE HEIGHT.
- 6. REFERENCE JEDEC REGISTRATION MO-211, VARIATION BC.

8-Bump micro SMD Package **NS Package Number TPA08EFA** $X_1 = 1.387$ $X_2 = 1.412$ $X_3 = 0.500$

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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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PRODUCTS DESIGN ORDER COMPANY

LMC555 - CMOS Timer



<u>Datasheet</u> <u>Packaging</u> <u>Samples & Pricing</u> <u>Reliability</u> <u>Design Tools</u> <u>Knowledge Base</u>

Features

- Less than 1 mW typical power dissipation at 5V supply
- 3 MHz astable frequency capability
- 1.5V supply operating voltage guaranteed
- Output fully compatible with TTL and CMOS logic at 5V supply
- Tested to -10 mA, +50 mA output current levels
- Reduced supply current spikes during output transitions
- Extremely low reset, trigger, and threshold currents
- Excellent temperature stability
- Pin-for-pin compatible with 555 series of timers
- Available in 8-pin MSOP Package and 8-Bump micro SMD package

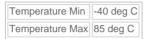
General Description

The LMC555 is a CMOS version of the industry standard 555 series general purpose timers. $\underline{\text{More...}}$

Typical Application

See Datasheet for Application Information

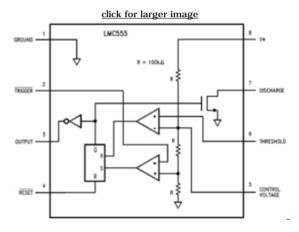
Parametric Table expand



Additional Resources

Design Tools (see below)

Connection Diagram



RoHS Compliance Information	Size in Kbytes	Date	203
LMC555 CMOS Timer	767 Kbytes	25-May-06	<u>View Online</u> <u>Download</u>
LMC555 CMOS Timer (Japanese) 本サイトの日本語版データシートは最新版ではない場合があります。ご検討 およびご採用に当たっては、最新の英語版データシートを必ずご確認ください。	513 Kbytes		ダウンロード
LMC555 Mil-Aero Datasheet MNLMC555-X	160 Kbytes		<u>Download</u>

If you have trouble printing or viewing PDF file(s), see Printing Problems.

Package Availability, Models, Samples & Pricing

	Package					Factory Lead Time			Samples &		Budgetary Pricing		<u>Package</u>			
Part Number	Туре	Pins	Spec.	MSL Rating	Peak Reflow	RoHS Report	CAD Symbols	<u>Weeks</u>	Qty	Models	Models Electronic Orders	Qty	\$US each	Pack Size	<u>Marking</u> <u>Format</u>	
LMC555CBPX	MICRO SMD	8	STD	1	260	RoHS	N/A	Lifetime b	ouy	N/A		1K+	\$0.48	reel	XVF	
EWOOOD DI X	<u>imorto omb</u>				200	110110	14// (12 weeks	15000		Buy Now		ψ0.40	3000	<u>l 1</u>	
			STD	1	235			Full produc	ction		Samples			rail	NSZXTT	
LMC555CM	SOIC NARROW	8	NOPB	1	260	RoHS N/A	6 weeks	5000	N/A	Buy Now	1K+	\$0.43	of 95	<u>LMC</u> <u>555CM</u>		
			STD	1	235			Full produc	ction					reel	NSZXTT	
LMC555CMX	SOIC NARROW	8	NOPB	1	260	RoHS	N/A	6 weeks	5000	N/A	Buy Now	1K+	\$0.43	of 2500	<u>LMC</u> <u>555CM</u>	
			STD	1	260			Full produc	ction		Samples			reel	ZXTT	
LMC555CMM	MINI SOIC	8	NOPB	1	260	RoHS	N/A	8 weeks	5000	N/A	Buy Now	1K+	\$0.50	of 1000	<u>ZC5</u>	
LMC555CMMX	MINI SOIC			STD	1	260			Full produc	ction					reel	ZXTT
			NOPB	1	260	RoHS	N/A	8 weeks 7500	7500	N/A	Buy Now	1K+	\$0.50	of 3500	<u>ZC5</u>	

LMC555CN	MDIP_	MDIP	8	STD	1	NA_	RoHS	N/A	Full produc	ction	N/A	Samples	1K+	\$0.54	rail of	NSUZXYTT LMC			
LIVICSSSCIA		<u>won</u>		NOPB	1	NA	110710	IN/A	6 weeks	3000	IN//X	Buy Now	INT	\$0.54	40	<u>555CN</u>			
LMC555CTP	MICRO SMD	8	NOPB	1	260	RoHS	N/A	Full produc	ction	N/A	Samples	1K+	\$0.59	reel	XVF				
LIVIOSSSOTI	IMIOIXO GIME		NOIB	'	200	IXONO	IN/A	6 weeks	N/A	IN/A	Buy Now	IIXŦ	ψ0.59	250	<u>l 02</u>				
LMC555CTPX	MICRO SMD	MICRO SMD		NOPB	1	260	RoHS	N/A	Full produc	ction	N/A		1K+	\$0.59	reel	XVF			
LIVICSSSCIFA		MICRO SMD 8						INOFB	'	200	1 110110		6 weeks	N/A	IN/A	Buy Now	IIXŦ	φ0.59	3000
LMC555 MDA	Unpackaged Die						Full produc	Full production N/A				CALL	tray	_					
LIVIOSSS WIDA			Опри	onagoa D	<u>10</u>			N/A	N/A	IN/A			CALL	N/A					
LMC555 MD8			Unnac	ckaged D)io			Full produc	ction	N/A			CALL	tray	_				
LIVIOSSS IVIDO			Опрас	okagea b	<u>//C</u>			N/A	N/A	IN/A			OALL	N/A	Ξ				
5962-8950305PA		CERDIP 8			DHS N/A	<u>Obsolete</u>						rail	NSZSSXXYYA LMC555J/883						
(LMC555J/883)	CERDIP		CERDIP 8	RoHS		8 weeks	500	N/A	N/A Buy Now	50+	\$11.70	of 40	Q 5962- 8950305PA						

Obsolete Parts

Obsolete Part	Alternate Part or Supplier	Source	Last Time Buy Date
LMC555CBP	NONE	NONE	07/24/2009
LMC555CBPX	NONE	NONE	07/24/2009
LMC555G-R DWF	NONE	NONE	04/04/95
LMC555H/883	LMC555J/883	NATIONAL SEMICONDUCTOR	09/08/98
LMC555J/883	LM555J/883	NONE	12/03/2008

General Description

The LMC555 is a CMOS version of the industry standard 555 series general purpose timers. In addition to the standard package (SOIC, MSOP, and MDIP) the LMC555 is also available in a chip sized package (8 Bump micro SMD) using National's micro SMD package technology. The LMC555 offers the same capability of generating accurate time delays and frequencies as the LM555 but with much lower power dissipation and supply current spikes. When operated as a one-shot, the time delay is precisely controlled by a single external resistor and capacitor. In the stable mode the oscillation frequency and duty cycle are accurately set by two external resistors and one capacitor. The use of National Semiconductor's LMCMOSTM process extends both the frequency range and low supply capability.

Reliability Metrics

1			1	1		1		1
LMC555 MD8	CMOS	0	16925	0	0	2065000	2	585949388
LMC555 MDA	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CBPX	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CM	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CMM	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CMMX	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CMX	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CN	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CTP	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555CTPX	P2CMOS	0	45010	0	1	3767500	3	484371054
LMC555J/883	CMOS	0	16925	0	0	2065000	2	585949388

PPM *

LTA Rejects

LTA Device Hours

306 Kbytes

20-Sep-02

Download

EFR Sample Size

MTTF (Hours)

FITS

Note: The Early Failure Rates were calculated as point estimates. The Long Term Failure Rates were calculated at 60% confidence using the Arrhenius equation at 0.7eV activation energy and derating the assumed stress temperature of 150°C to an application temperature of 55°C.

For more information on Reliability Metrics, please click here.

Process

Title	Size in Kbytes	Date	POF		
LMC555CBP Micro SMD Qualification Package	4172 Kbytes	17-Apr-2000	<u>View Online</u>	<u>Download</u>	

If you have trouble printing or viewing PDF file(s), see Printing Problems.

AN-460: Application Note 460 LM34/LM35 Precision Monolithic Temperature Sensors

EFR Reject

Application Notes

Design Tools

Part Number

Title	Size in Kbytes	Date	POF
AN-828: Application Note 828 Increasing the High Speed Torque of Bipolar Stepper Motors	808 Kbytes	1-Oct-02	Download
AN-828 (Japanese): Application Note 828 Increasing the High Speed Torque of Bipolar Stepper Motors 本サイトの日本語アプリケーション・ノートは最新版でない場合があります。ご検討およびご採用にあたっては、必ず最新の英語版アプリケーション・ノートをご確認ください。	362 Kbytes		ダウンロード
AN-681: PC Mouse Implementation Using COP800	525 Kbytes	5-Aug-95	<u>Download</u>

AN-460 (Japanese): Application Note 460 LM34/LM35 Precision Monolithic Temperature Sensors		
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